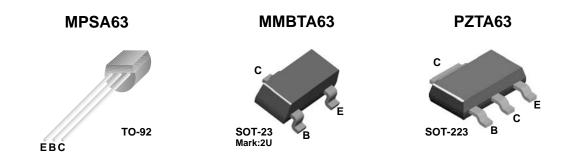


August 2010

MPSA63 / MMBTA63 / PZTA63 PNP Darlington Transistor

Features

- This device is designed for applications requiring extremely high current gain at currents to 800 mA.
- Sourced from Process 61.



Absolute Maximum Ratings * T_a = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CES}	Collector-Emitter Voltage	-30	V
V _{CBO}	Collector-Base Voltage	-30	V
V _{EBO}	Emitter-Base Voltage	-10	V
I _C	Collector Current - Continuous	-1.2	А
T _{J,} T _{stg}	Operating and Storage Junction Temperature Range	- 55 to +150	°C

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics T_a = 25°C unless otherwise noted

Symbol	Parameter	Max.			Units
		MPSA63	*MMBTA63	**PZTA63	Oille
P _D	Total Device Dissipation Derate above 25°C	625 5.0	350 2.8	1,000 8.0	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3			°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	125	°C/W

^{*} Device mounted on FR-4 PCB 1.6" \times 1.6" \times 0.06".

^{**} Device mounted on FR-4 PCB 36mm × 18mm × 1.5mm; mounting pad for the collector lead min. 6cm².

Electrical Characteristics $T_a = 25$ °C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units	
Off Characteris	Off Characteristics					
BV _{(BR)CES}	Collector-Emitter Breakdown Voltage	$I_C = -100 \mu A, I_B = 0$	-30		V	
I _{CBO}	Collector-Cutoff Current	$V_{CB} = -30V, I_{E} = 0$		-100	nA	
I _{EBO}	Emitter-Cutoff Current	$V_{EB} = -10V, I_{C} = 0$		-100	nA	
On Characteris	On Characteristics *					
h _{FE}	DC Current Gain	I _C = -10mA, V _{CE} = -5.0V I _C = -100mA, V _{CE} = -5.0V	5,000 10,000			
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_C = -100 \text{mA}, I_B = -0.1 \text{mA}$		-1.5	V	
V _{BE(on)}	Base-Emitter On Voltage	$I_C = -100 \text{mA}, V_{CE} = -5.0 \text{V}$		-2.0	V	
Small Signal Characteristics						
f _T	Current Gain - Bandwidth Product	I _C = -10mA, V _{CE} = -5.0V, f = 100MHz	125		MHz	

^{*} Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2.0%

Typical Performance Characteristics

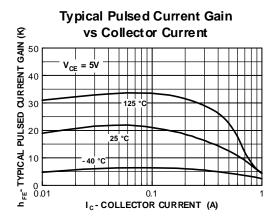


Figure 1. Typical Pulsed Current Gain vs Collector Current

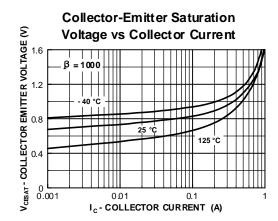


Figure 2. Collector-Emitter Saturation Voltage vs Collector Current

Typical Performance Characteristics (continued)

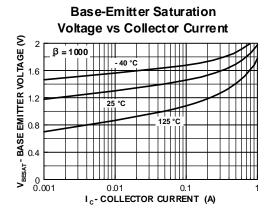


Figure 3. Base-Emitter Saturation Voltage vs Collector Current

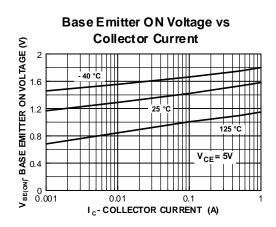
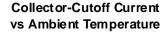


Figure 4. Base-Emitter On Voltage vs Collector Current



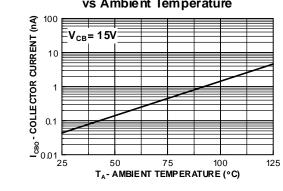


Figure 5. Collector Cutoff Current vs Ambient Temperature

Input and Output Capacitance vs Reverse Bias Voltage

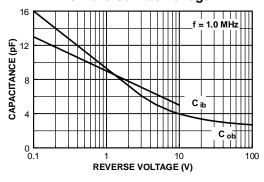


Figure 6. Input and Output Capacitance vs Reverse Bias Voltage

Power Dissipation vs Ambient Temperature

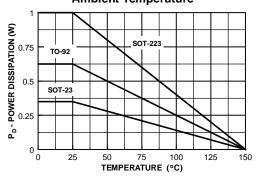


Figure 7. Power Dissipation vs Ambient Temperature





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Definition of Terms

Definition of Terms		
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